



jee

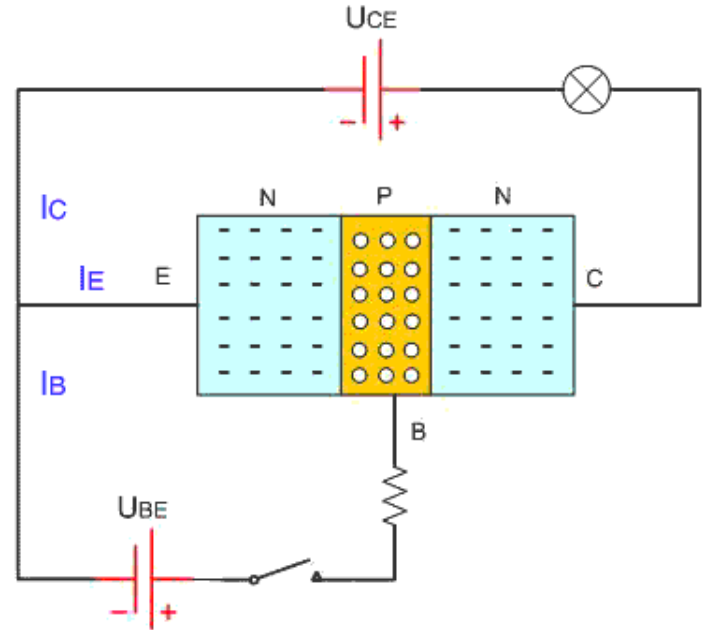


LIVE daily

# Semiconductors

## Lecture - 3

### Transistor



# Jayant Nagda

Physics Educator

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B.Tech, **IIT Bombay**

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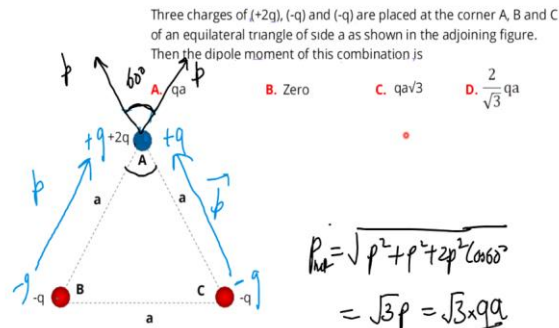




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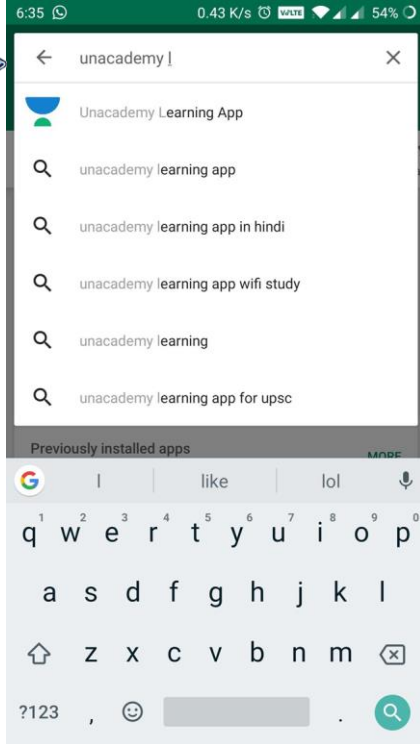
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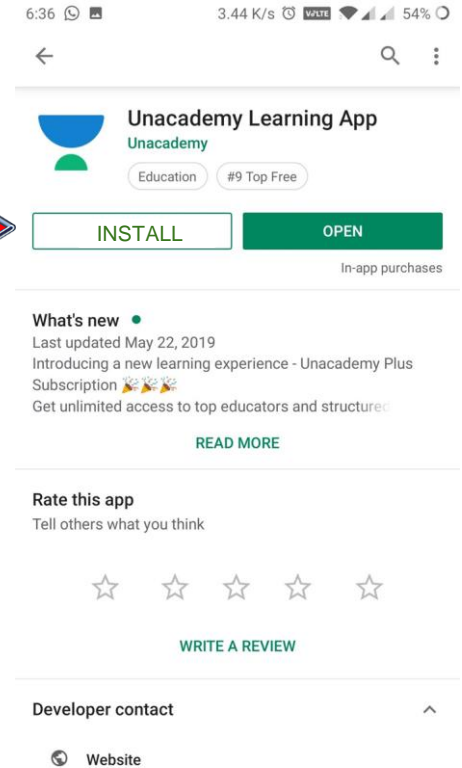
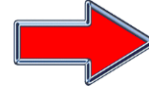
Lesson 46 • Today, 10:00 PM

Kailash Sharma

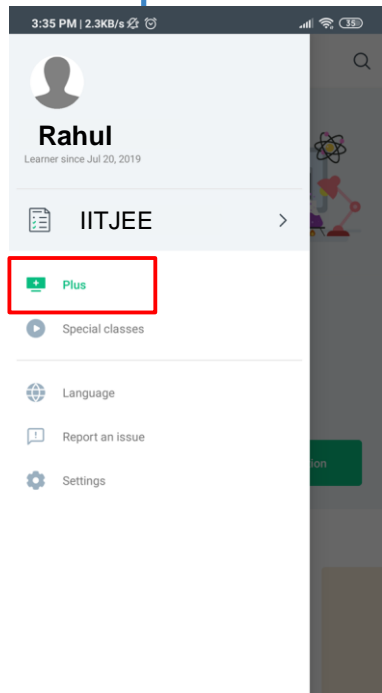
# Step 1



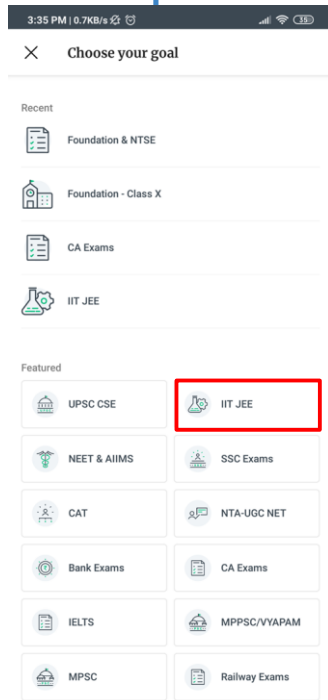
# Step 2



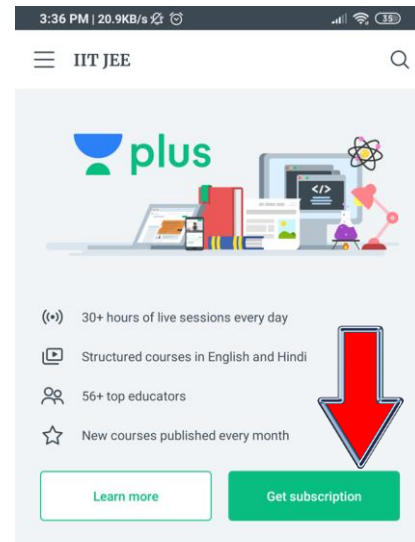
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## Step 4



## Step 5



# Step 6

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# Transistor



It is a three terminal Semiconductor Device

Transistor: Transfer + Resistor

Current is transferred from Low Resistance to High Resistance circuit

Transistor is used for rectification, amplification, oscillation etc.

# Transistor

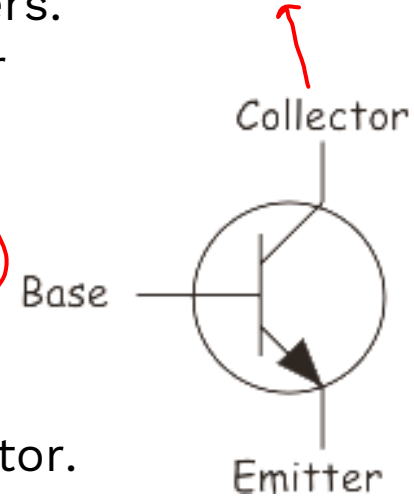


1. **Emitter** : Heavily Doped crystal supplies/emits majority charge carriers. Moderate Size: thinner than collector and thicker than base

2. **Base** : Lightly Doped crystal (*Light*) and made very thin. It passes most of the emitter injected charge carriers to the collector.

3. **Collector** : Moderately Doped crystal thickest in size. Collects/removes majority charge carriers coming from emitter.

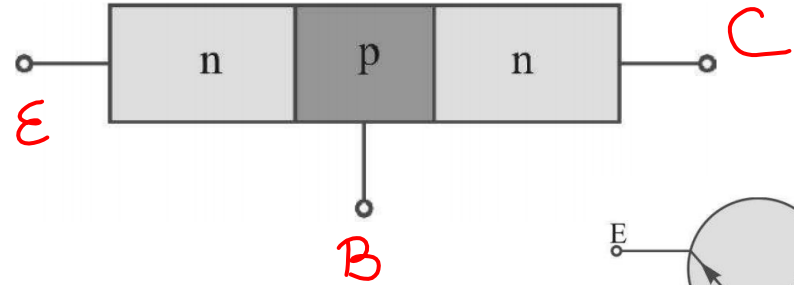
(moderate) collected



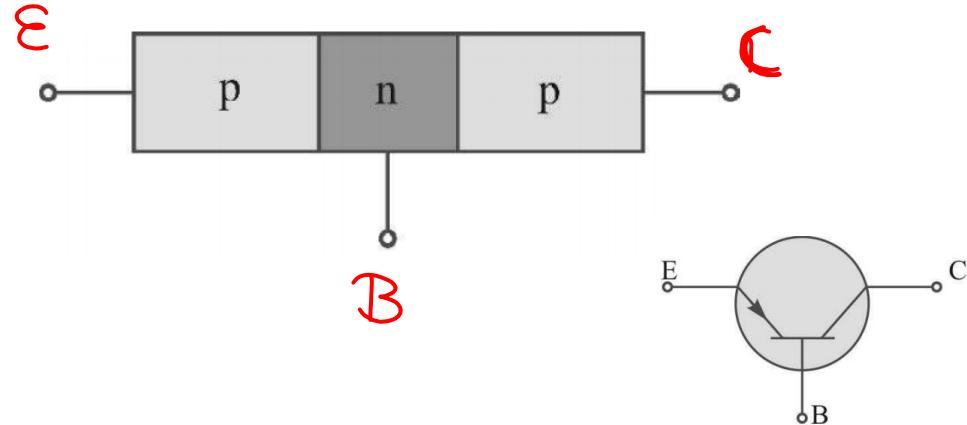
emit (high)

# Transistor

A p-type crystal  
sandwiching between  
two n-type crystals

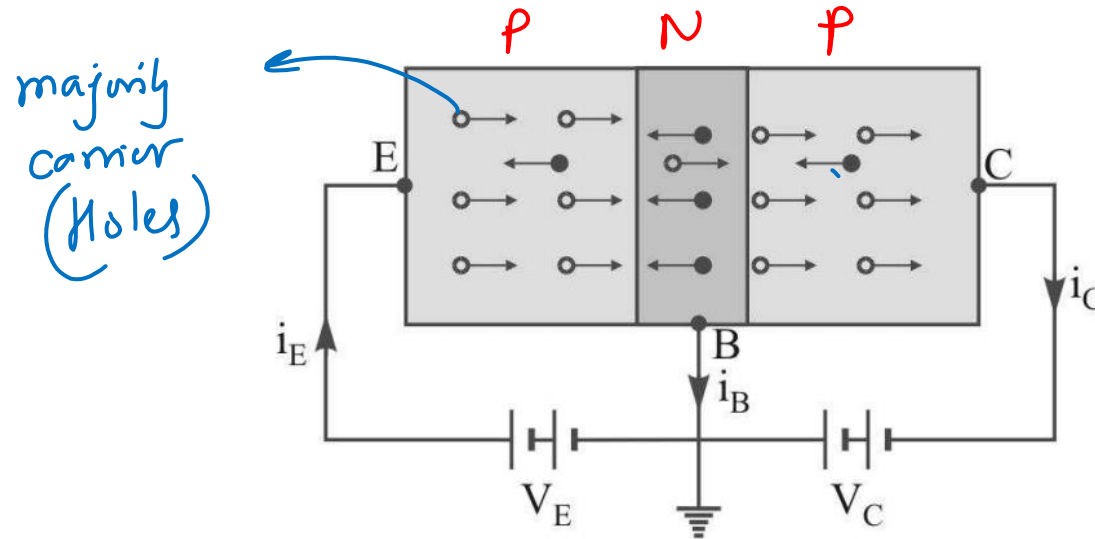


A n-type crystal  
sandwiching between  
two p-type crystals



# Working of a p-n-p Transistor

Base is common with Emitter and Collector



Emitter-Base junction is given small forward bias

Collector-Base junction is given large reverse bias

# Working of a p-n-p Transistor

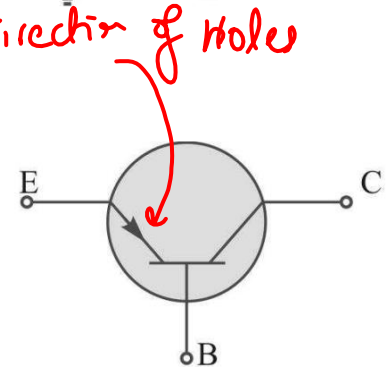
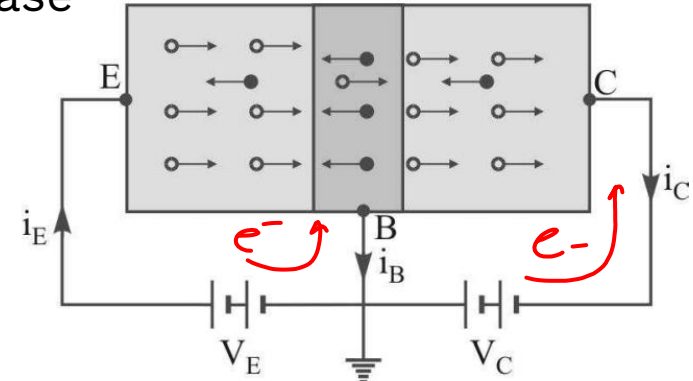
holes move from emitter towards base

Most of them (nearly 98%)  
cross base and enter  
into collector region

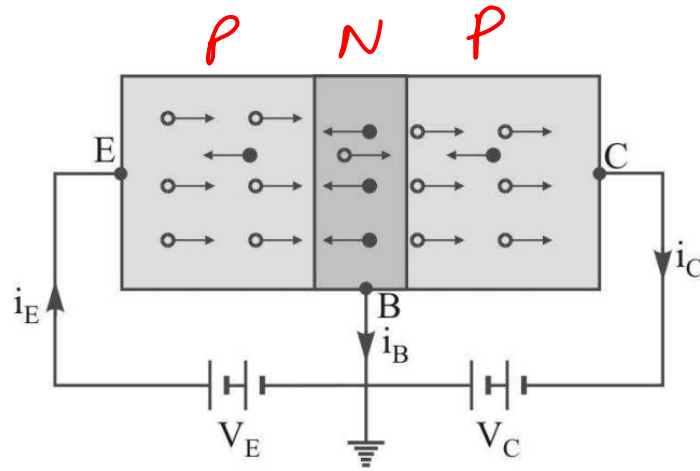
while very few (nearly 2%)  
combine with the electrons in base  
an electron leaves the negative terminal of  
battery  $V_E$  and enters into base.

This causes a small base current  $I_B$

The holes entering into the collector region  
combine with the electrons coming from the  
negative terminal of  $V_C$ . This causes collector  
current  $I_C$



# Working of a p-n-p Transistor



$$i_E = i_B + i_C$$

(2-10%) of  $i_E$  (90-98%) of  $i_E$

1. The base current may be nearly 2 to 10% of the emitter current depending on the doping level. Similarly collector current may be nearly 90 to 98% of the emitter current.
2. The holes are the charge carriers within the transistor while electrons are charge carriers in external circuit.



## Example

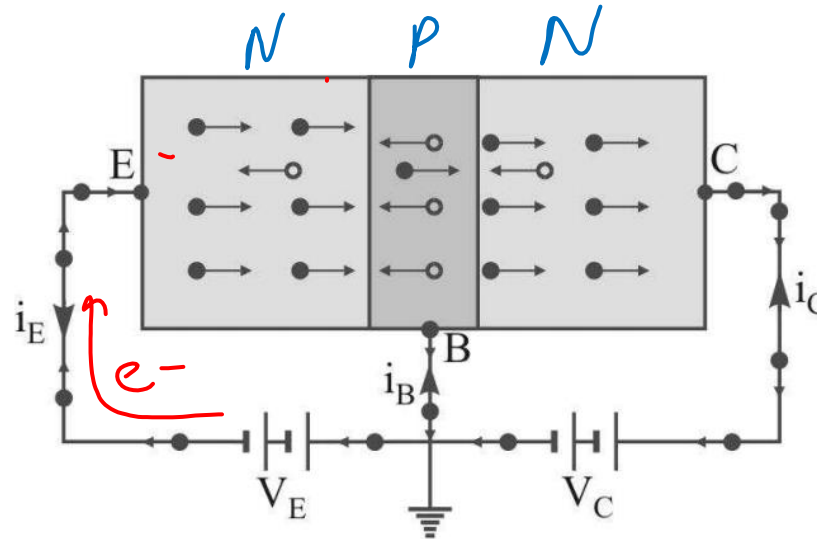
### MCQ type Question [ +4 , -1]

The emitter-base junction of a transistor is *forward* biased while the collector base junction is *Rev* biased.

- A.** forward, forward
- B.** forward, reverse
- C.** reverse, forward
- D.** reverse, reverse

# Working of a n-p-n Transistor

Base is common with Emitter and Collector



Emitter-Base junction is given small forward bias

Collector-Base junction is given large reverse bias



# Working of a n-p-n Transistor

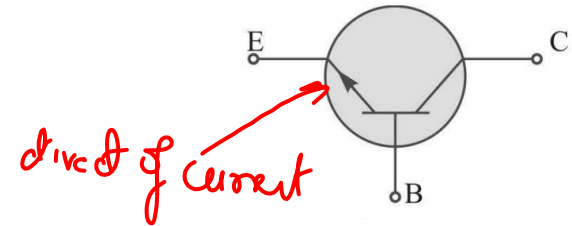
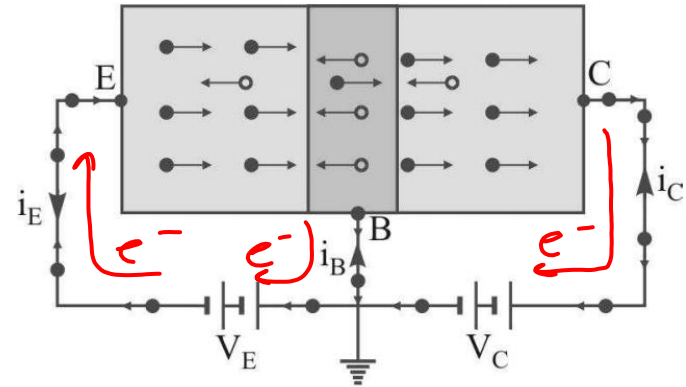
forward bias in emitter-base region,  
electrons from emitter region  
move towards base.

Most of them (nearly 98%)  
cross the base  
and enter into collector region

while very few (nearly 2%)  
combine with the holes in base

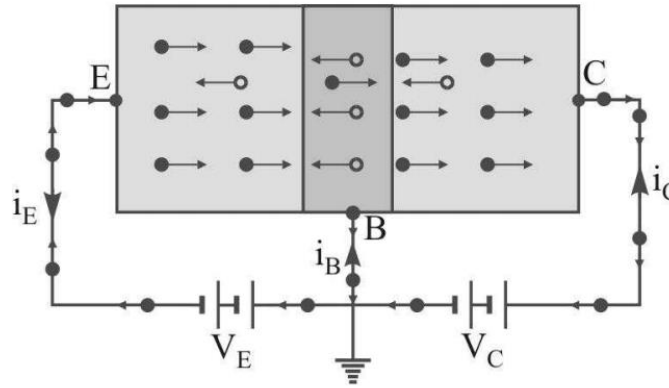
light

This electron is captured by positive terminal of the battery  $V_E$  and  
send it towards emitter region. This causes a small base current  $I_B$ .  
The electrons entering into collector region are attracted by the  
positive terminal of  $V_C$ . This causes collector current  $I_C$ .



# Working of a n-p-n Transistor

These two currents combine together constitute emitter current  $i_E$ . Thus



$$i_E = i_B + i_C$$

(2-10%) of  $i_E$  (90-98% of  $i_E$ )

1. The base current may be 2 to 10% of the emitter current depending on the doping level. Similarly collector current may be 90 to 98% of the emitter current.
2. The electrons are the charge carriers within the transistor as well as in external circuit.

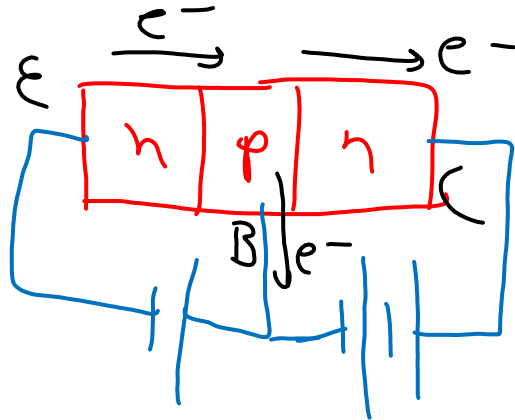


## Example

### MCQ type Question [ +4 , -1 ]

In an n-p-n transistor -

- A. holes move from emitter to base.
- B. negative charge carrier move from emitter to base.
- C. holes move from base to collector.
- D. negative charge carrier move from collector to base



# Transistor Configurations

A transistor can be connected in the circuit in the following three ways :

1. Common base (CB) connection.
2. Common emitter (CE) connection.
3. Common collector (CC) connection.

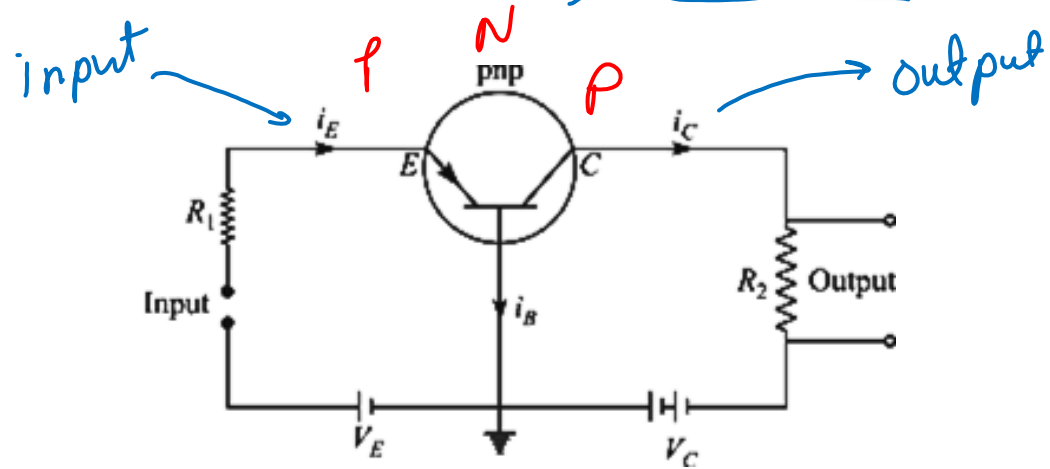
first two are commonly used in practice

Each circuit connection has specific advantage and disadvantage

In all configurations the emitter is always connected with small forward bias, while the collector always has a large reverse bias

## Common Base Connection

The input is applied between emitter and base and output is taken from collector base

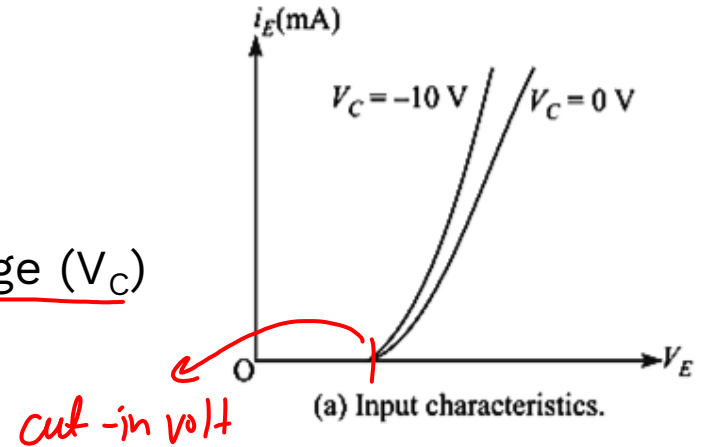


A p-n-p transistor in common base connection

# Common Base Connection

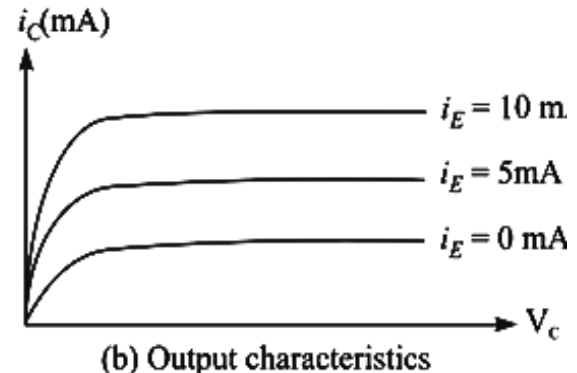
## Input characteristics

Shows variation of emitter current ( $i_E$ ) with emitter voltage ( $V_E$ ) at constant collector voltage ( $V_C$ )



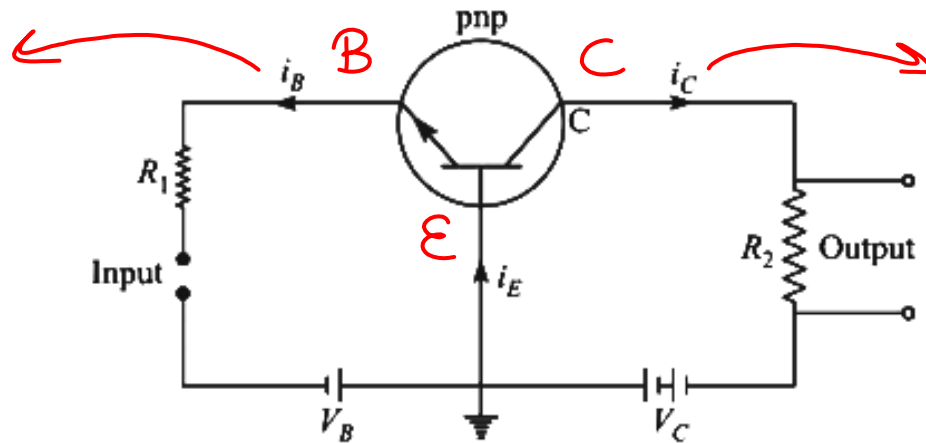
## Output characteristics

Shows the variation of collector current ( $i_C$ ) with collector voltage ( $V_C$ ) at constant emitter current ( $i_E$ )



## Common Emitter Connection

The input is applied between base and emitter and output is taken from collector and emitter

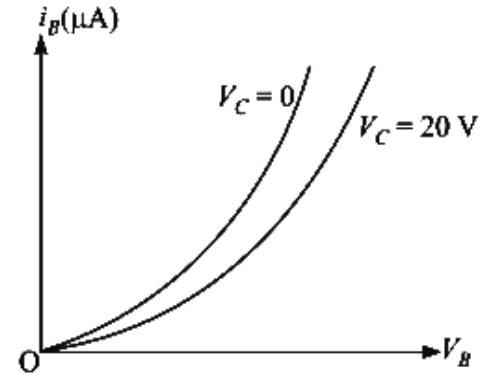


A p-n-p transistor in common emitter connection

# Common Emitter Connection

## Input characteristics

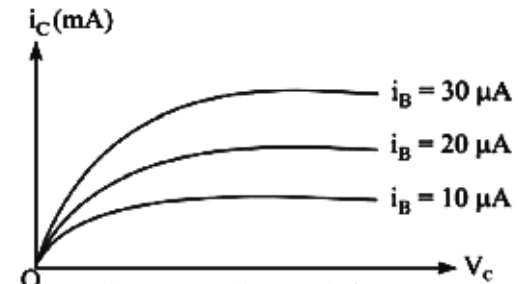
Variation of base current  $i_B$   
with base voltage  $V_B$   
at constant collector voltage  $V_C$



(a) Input characteristics.

## Output characteristics

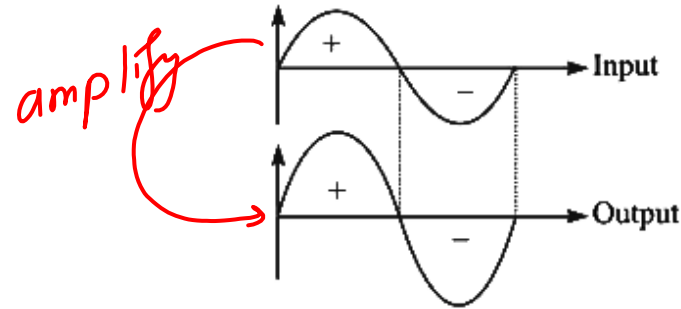
Variation of collector current  $i_C$   
with collector voltage  $V_C$   
at constant base current  $i_B$



(b) Output characteristics.



A transistor can be used for amplification in which strength of output signal is more than input signal.

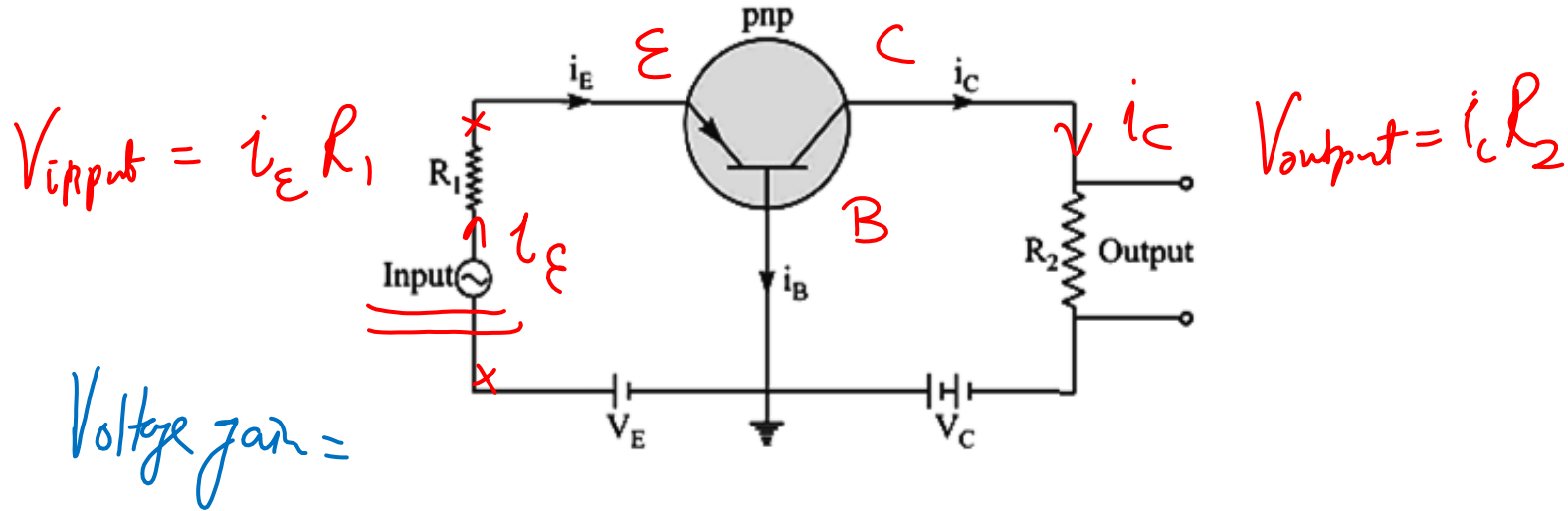


The transistor can be used as an amplifier in the following three configurations

1. CB amplifier
2. CE amplifier
3. CC amplifier

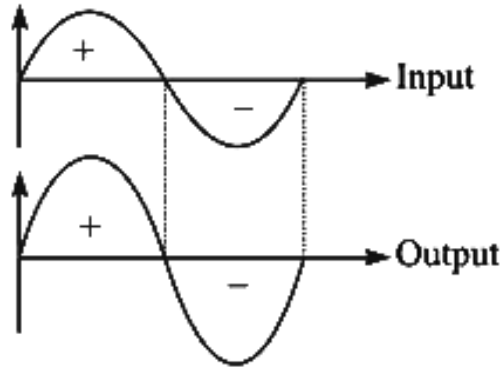
# CB Transistor Amplifier

A pnp transistor in common-base-connection



Input signal is fed between the emitter and base

## CB Transistor Amplifier



(b) Input and output signals.

$$\text{input voltage} = i_E R_1$$

$$\text{output voltage} = i_C R_2$$

$$\text{Voltage gain} = \frac{\text{Output voltage}}{\text{Input voltage}} = \frac{i_C R_2}{i_E R_1}$$

The output signal is in phase with input signal.

The current gain  $\alpha$  is defined as :

$$\alpha = \frac{[\text{Change in collector current}]}{[\text{Change in emitter current}]} , V_c \text{ Constant}$$

$$\boxed{\alpha = \frac{\Delta i_C}{\Delta i_E}}^* , V_c \text{ Constant}$$

The value of  $\alpha$  ranges from 0.9 to 0.99.

$$\left( i_E = i_C + i_B \right)$$
$$i_C < i_E$$

For dc signal,

$$\boxed{\alpha = \frac{i_C}{i_E}}^*$$



## Example

### MCQ type Question [ +4 , -1 ]

In a common base transistor circuit, the current gain is 0.98. On changing emitter current by 5.00 mA, the change in collector current is -

- A. 0.196 mA
- B. 2.45 mA
- C. 4.9 mA
- D. 5.1 mA

$$\alpha = 0.98$$

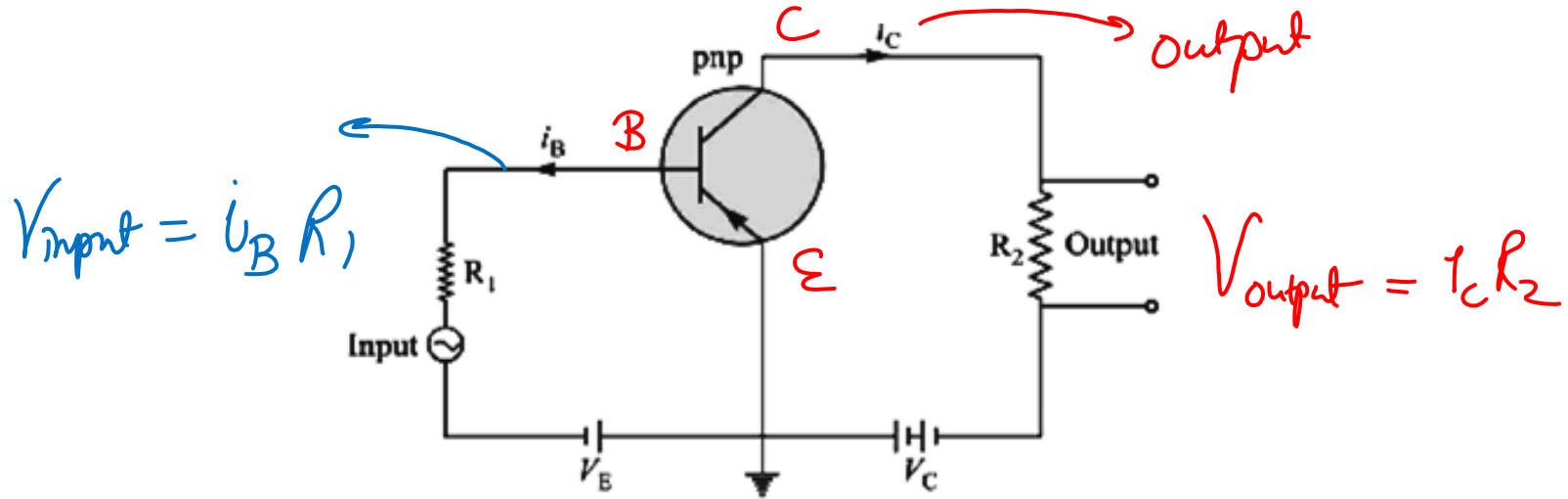
$$\Delta i_e = \Delta i_{\text{input}} = 5 \text{ mA}$$

$$\Delta i_c = \Delta i_{\text{output}} = ?$$

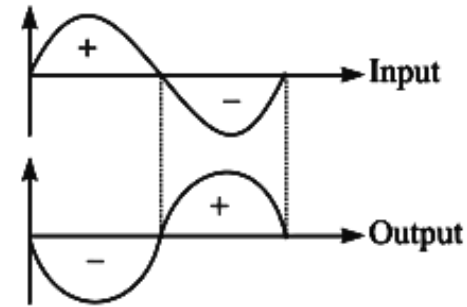
$$\alpha = \frac{\text{output}}{\text{input}}$$

$$\Delta i_c = \alpha \Delta i_e \\ = 0.98 \times 5 \text{ mA}$$

A pnp transistor in common emitter connection



Input signal is fed between the base and emitter



(b) Input and output signals.

Power gain

$$= \frac{P_{\text{output}}}{P_{\text{input}}}$$

$$= \frac{I_{\text{output}} V_{\text{output}}}{I_{\text{input}} V_{\text{input}}}$$

$$\text{input voltage} = i_B R_1 \quad \text{output voltage} = I_C R_2$$

$$\text{Voltage gain} = V_{\text{output}} / V_{\text{input}} = i_C R_2 / i_B R_1$$

$$\text{Power gain} = \text{Current gain} \times \text{Voltage gain}$$

The output signal is out of phase with the input signal.

The current gain  $\beta$  is defined as :

$$\beta = \frac{[\text{Change in collector current}]}{[\text{Change in base current}]} , V_c \text{ Constant}$$

$$\boxed{\beta = \frac{\Delta i_C}{\Delta i_B}}^* V_c \text{ Constant}$$

The value of  $\beta$  ranges from 20 to 200

For dc  
signal,

$$\boxed{\beta = \frac{i_C}{i_B}}$$

$$i_E = i_B + i_C$$

Small  
(2-10-1)



## Example

### MCQ type Question [ +4 , -1 ]

A common emitter transistor amplifier has a current gain of 50. If the load resistance is  $4\text{k}\Omega$  and input resistance is  $500\Omega$  the voltage gain of the amplifier -

$$R_i = 500\Omega$$

A. 160

B. 200

☒ C. 400

D. None

$$R_{out} = 4000$$

$$V_{gain} = \frac{V_o}{V_i} = \left( \frac{I_o}{I_i} \right) \times \frac{R_o}{R_i} = 50 \times \frac{4000}{500} = \underline{\underline{400}}$$

## Relationship between $\alpha$ and $\beta$


$$I_E = I_B + I_C$$

$$\frac{I_E}{I_C} = \frac{I_B}{I_C} + 1$$

$$\Rightarrow \frac{1}{\alpha} = \frac{1}{\beta} + 1$$

$$\Rightarrow \frac{1}{\alpha} - 1 = \frac{1}{\beta} \Rightarrow \boxed{\beta = \frac{\alpha}{1-\alpha}}^*$$

## Relationship between $\alpha$ and $\beta$

$$I_E = I_B + I_C$$

$$\Delta I_E = \Delta I_B + \Delta I_C$$

$$\frac{\Delta i_E}{\Delta i_C} = \frac{\Delta i_B}{\Delta i_C} + 1$$

$$\alpha = \frac{\beta}{1 + \beta}$$

$$\beta = \frac{\alpha}{1 - \alpha}$$



## Example

### MCQ type Question [ +4 , -1 ]

For a transistor,  $\alpha = 0.9$ , the value of  $\beta$  is -

**A.** 1

**B.** 0.09

**C.** 0.9

**D.** 9

$$\beta = \frac{\alpha}{1-\alpha} = \frac{0.9}{1-0.9} = 9$$

# Daily Practice Problems

A word cloud centered on a dark blue background, featuring various terms related to electronics and technology. The words are arranged in a roughly circular shape, with some words appearing in a larger, bolder font than others. The colors of the words are primarily white and light blue.

INDUSTRY  
SYSTEM PROCESSOR MICROPROCESSOR  
DIGITAL COMPONENT  
WAFER ELECTRICAL  
ELECTRONICS EQUIPMENT  
INDUSTRIAL MICRO BOARD  
CIRCUIT CIRCUIRY  
INFORMATION  
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MANUFACTURING  
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MICROELECTRONIC  
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CPU MICROCHIP COMPUTER  
ENGINEERING MOTHERBOARD SCIENCE  
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POWER



## Example

### MCQ type Question [ +4 , -1]

The part of a transistor which is most heavily doped to produce large number of majority carriers is

**[AIEEE 2002]**

- A.** Emitter
- B.** Base
- C.** Collector
- D.** Can be any of the above three.

Ans: A



## Example

### MCQ type Question [ +4 , -1 ]

If  $l_1$ ,  $l_2$ ,  $l_3$  are the lengths of the emitter, base and the collector of a transistor, then -

**A.**  $l_1 = l_2 = l_3$

**B.**  $l_1 < l_2 > l_3$

**C.**  $l_1 < l_2 < l_3$

**D.**  $l_1 > l_2 > l_3$

Ans: D



## Example

### MCQ type Question [ +4 , -1 ]

To use transistor as an amplifier -

- A.** Emitter-base junction is forward biased and collector base junction is reverse biased.
- B.** Both junctions are forward biased.
- C.** Both junctions are reverse biased.
- D.** It does not matter how the transistor is biased. It always works as an amplifier

Ans: A





## Example

### MCQ type Question [ +4 , -1 ]

When npn transistor is used as an amplifier

**[AIEEE 2003]**

- A. Electrons move from collector to base
- B. Holes move from emitter to base
- C. Electrons move from base to collector
- D. Holes move from base to emitter

Ans: D

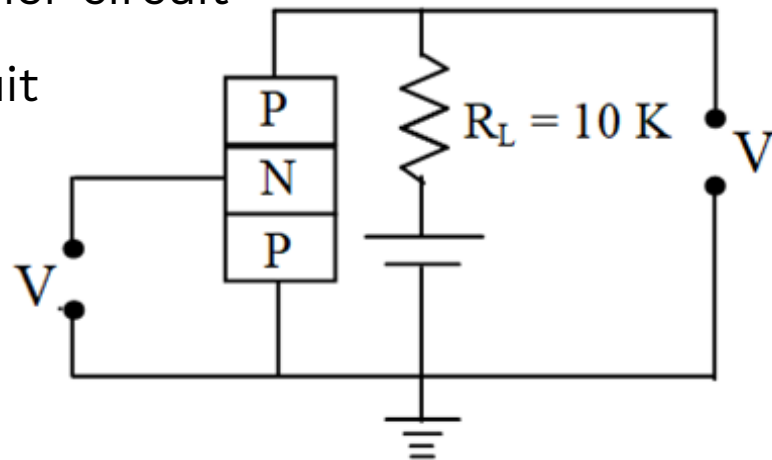


## Example

### MCQ type Question [ +4 , -1 ]

An P-N-P transistor circuit is arranged as shown. It is a –

- A.** Common base amplifier circuit
- B.** Common emitter amplifier circuit
- C.** Common collector circuit
- D.** None



Ans: C

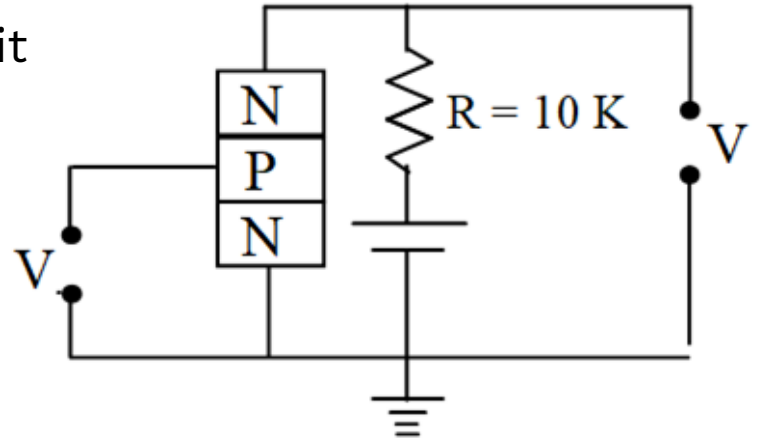


## Example

### MCQ type Question [ +4 , -1 ]

An N-P-N transistor circuit is arranged as shown. It is a –

- A.** Common base amplifier circuit
- B.** Common emitter amplifier circuit
- C.** Common collector circuit
- D.** None



Ans: B



## Example

### MCQ type Question [ +4 , -1 ]

In a common base amplifier, the phase difference between the input voltage and output voltage is

**[AIEEE 2005]**

**A.**  $\pi$

**B.**  $\pi/4$

**C.**  $\pi/4$

**D.** 0

Ans: D



## Example

### MCQ type Question [ +4 , -1]

For a transistor working as common base amplifier, the emitter current is 7.2 mA. The current gain is 0.96. The collector current is -

- A.**  $0.96 \times 7.2 \text{ mA}$       **B.**  $0.96/0.72 \text{ mA}$
- C.**  $0.96 - 7.2 \text{ mA}$       **D.**  $7.2 \text{ A} - 2 \times 0.96 \text{ mA}$



## Example

### MCQ type Question [ +4 , -1 ]

In a common base mode of a transistor, the collector current is 5.488 mA for an emitter current of 5.60 mA. The value of the base current amplification factor ( $\beta$ ) will be

**[AIEEE 2006]**

**A.** 49

**B.** 50

**C.** 51

**D.** 48



## Example

### MCQ type Question [ +4 , -1 ]

An n-p-n transistor circuit has  $\alpha = 0.985$ . If  $I_c = 2\text{mA}$ , then value of  $I_B$  is -

- A.** 0.03 mA
- B.** 0.66 mA
- C.** 0.003 mA
- D.** 0.015 mA

Ans: C



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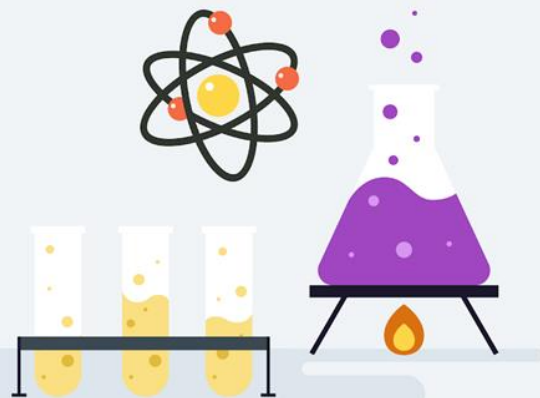


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